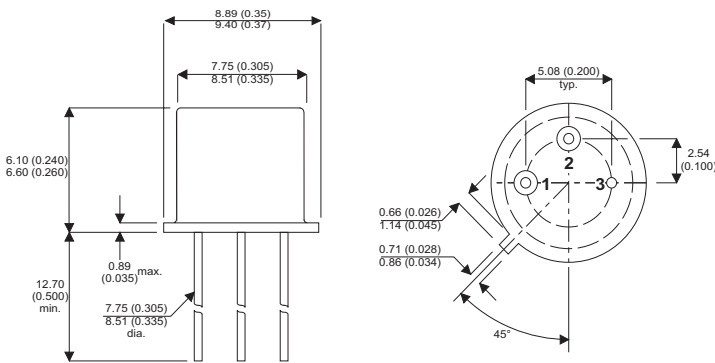


**MECHANICAL DATA**

Dimensions in mm (inches)



**HIGH VOLTAGE, HIGH CURRENT  
SILICON EXPITAXIAL PLANAR  
NPN TRANSISTOR**

**APPLICATIONS**

**Intended for High Voltage, High Current,  
Switching Applications up to 7A.**

**TO-39 PACKAGE**

Pin 1 – Emitter      Pin 2 – Base      Pin 3 – Collector

**ABSOLUTE MAXIMUM RATINGS** ( $T_{case} = 25^{\circ}C$  unless otherwise stated)

			<b>BUY47</b>	<b>BUY48</b>
$V_{CBO}$	Collector – Base Voltage	( $I_E = 0$ )	150V	200V
$V_{CEO}$	Collector – Emitter Voltage	( $I_B = 0$ )	120V	170V
$V_{EBO}$	Emitter – Base Voltage	( $I_C = 0$ )		6V
$I_C$	Collector Current			7A
$I_{CM}$	Peak Collector Current (repetitive)			10A
$P_{tot}$	Total Power Dissipation	@ $T_{amb} \leq 25^{\circ}C$		1W
		@ $T_{case} \leq 50^{\circ}C$		10W
$T_{STG}$	Storage Temperature Range			-65 to +200°C
$T_J$	Maximum Operating Junction Temperature			200°C

**ELECTRICAL CHARACTERISTICS**

 (T<sub>case</sub> = 25°C unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit	
I <sub>CBO</sub> Collector Cut-off Current	V <sub>CB</sub> = 80V I <sub>E</sub> = 0	<b>BUY47</b>		10	μA	
		T <sub>C</sub> = 125°C		1	mA	
	V <sub>CB</sub> = 100V I <sub>E</sub> = 0	<b>BUY48</b>		10	μA	
		T <sub>C</sub> = 125°C		1	mA	
V <sub>(BR)CBO</sub> * Collector – Base Breakdown Voltage	I <sub>C</sub> = 1mA I <sub>E</sub> = 0	<b>BUY47</b>		150	V	
		<b>BUY48</b>		200		
V <sub>CEO(sus)</sub> * Collector – Emitter Sustaining Voltage	I <sub>C</sub> = 20mA I <sub>B</sub> = 0	<b>BUY47</b>		120	V	
		<b>BUY48</b>		170		
V <sub>EBO</sub> * Emitter – Base Voltage	I <sub>E</sub> = 1mA I <sub>C</sub> = 0			6	V	
V <sub>CE(sat)</sub> * Collector – Emitter Saturation Voltage	I <sub>C</sub> = 0.5A I <sub>B</sub> = 50mA			0.05	V	
	I <sub>C</sub> = 2A I <sub>B</sub> = 0.2A			0.45		
	I <sub>C</sub> = 5A I <sub>B</sub> = 0.5A			1		
V <sub>BE(sat)</sub> * Base – Emitter Saturation Voltage	I <sub>C</sub> = 0.5A I <sub>B</sub> = 50mA			0.8	V	
	I <sub>C</sub> = 2A I <sub>B</sub> = 0.2A			1.1		
	I <sub>C</sub> = 5A I <sub>B</sub> = 0.5A			1.5		
h <sub>FE</sub> * DC Current Gain	I <sub>C</sub> = 50mA V <sub>CE</sub> = 5V			130	—	
	I <sub>C</sub> = 0.5A V <sub>CE</sub> = 5V	40	150			
	I <sub>C</sub> = 2A V <sub>CE</sub> = 5V	40	130			
	I <sub>C</sub> = 5A V <sub>CE</sub> = 5V	15	45			
f <sub>T</sub> Transition Frequency	I <sub>C</sub> = 100mA V <sub>CE</sub> = 10V			90	MHz	
C <sub>CBO</sub> Collector – Base Capacitance	I <sub>E</sub> = 0 f = 1MHz V <sub>CB</sub> = 50V			45	80	pF
t <sub>on</sub> Turn-On Time	I <sub>C</sub> = 5A V <sub>CC</sub> = 40V			1	μs	
t <sub>off</sub> Fall Time	I <sub>B1</sub> = -I <sub>B2</sub> = 0.5A			2		

**NOTES**

 \* Pulse Test: t<sub>p</sub> = 300μs, δ = 1.5%